





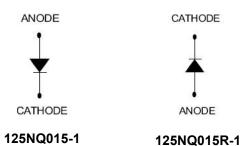
## 125NQ015/R-1 SCHOTTKY RECTIFIER



#### **Features**

- 125℃ T<sub>J</sub> operation
- Unique high power, Half-Pak module
- Replaces three parallel DO-5'S
- Easier to mount and lower profile than DO-5'S
- High purity, high temperature epoxy encapsulation for enhanced
- mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Base plate: Nickel plated; Terminals: Nickel plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Circuit Diagram**



# Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- · Reverse battery protection

The top side is terminal, the bottom side is base plate.

### Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	15(DC) 25(Working)	V
Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle @T <sub>C</sub> =71°C, rectangular wave form	120	А
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse	2040	Α
Non-Repetitive Avalanche Energy	E <sub>AS</sub>	T <sub>J</sub> =25℃,I <sub>AS</sub> =2A,L=4.5mH	9	mJ
Repetitive Avalanche Current	lar	Current decaying linearly to zero in 1 µsec Frequency limited by $T_J$ max. $V_A$ =1.5× $V_R$ typical	2	А

- China Germany Korea Singapore United States
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### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	\ \/	@ 120A, Pulse, T <sub>J</sub> = 25 °C	0.40	0.41	V
	V <sub>F1</sub>	@ 240A, Pulse, T <sub>J</sub> = 25 °C	0.50	0.52	V
	V	@ 120A, Pulse, T <sub>J</sub> = 125 °C	0.31	0.33	V
	$V_{F2}$	@ 240A, Pulse, T <sub>J</sub> = 125 °C	0.38	0.45	V
Reverse Current*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25 °C	11	40	mA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 100 °C	330	2000	mA
	I <sub>R3</sub>	@V <sub>R</sub> = 12V, T <sub>J</sub> = 100 °C	295	1780	mA
	I <sub>R4</sub>	@V <sub>R</sub> = 5V, T <sub>J</sub> = 100 °C	220	1080	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 \text{ °C}$ $f_{SIG} = 1MHz$	6650	7700	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

 $<sup>^*</sup>$  Pulse width < 300  $\mu$ s, duty cycle < 2%

# **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification		Units
Junction Temperature	TJ	-	-55 to +125		°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150		°C
Typical Thermal Resistance Junction to Case	$R_{ heta JC}$	DC operation	0.25		°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.07		°C/W
Mounting Torque	Тм	Non-lubricated threads	Mounting Torque	23(min) 29(max)	- Kg-cm
			Terminal Torque	35(min) 46(max)	
Approximate Weight	wt	-	36		g
Case Style	PRM1-1				

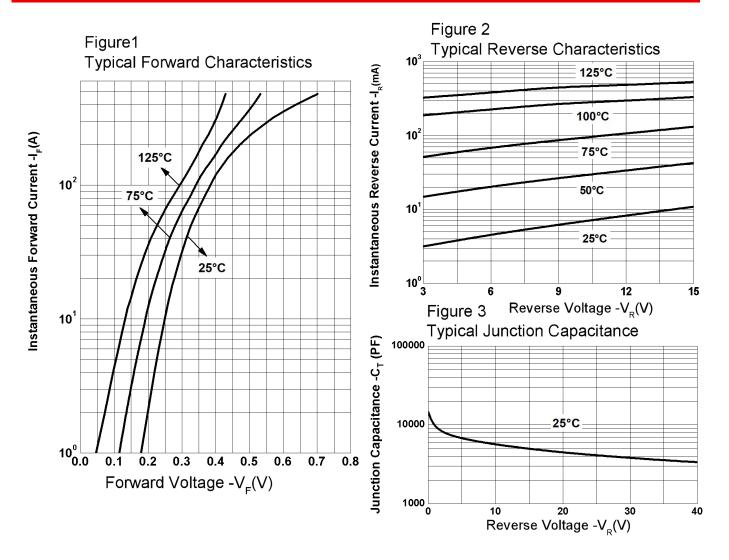
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# **Ratings and Characteristics Curves**



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# **Ordering Information**

Device	Package	Shipping	
125NQ015(R)-1	PRM1-1(Pb-Free)	27pcs/ box	

# **Marking Diagram**

SS XXXX 2nd rov SS 125NQ015-1 YY WW

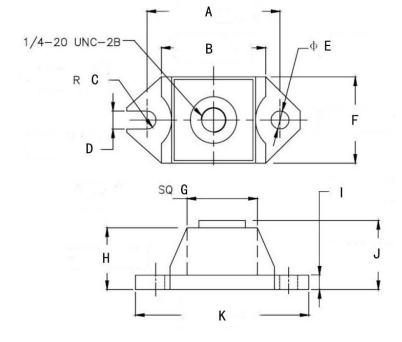
Where XXXX is YYWW

1st row SS YYWW
2nd row 125NQ015-1
SS = SS
YY = Year
WW = Week

Cautions: Molding resin

Epoxy resin UL:94V-0

### **Mechanical Dimensions PRM1-1 (Inches/Millimeters)**



SYMBOL	Millimeters		Inches		
	Min.	Max.	Min.	Max.	
Α	29.35	30.95	1.155	1.219	
В	24.77	26.04	0.975	1.026	
С	1.79	2.19	0.070	0.087	
D	3.73	4.24	0.146	0.167	
Е	3.73	4.24	0.146	0.167	
F	18.42	19.69	0.725	0.775	
G	18.55	19.55	0.730	0.770	
Н	13.59	14.47	0.535	70.500	
I	3.05	3.90	0.120	0.154	
J	14.87	15.87	0.585	0.625	
К	38.61	39.62	1.520	1.560	

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